



Vishay General Semiconductor

High Current Density Surface Mount Glass-Passivated Rectifiers

eSMP™ Series



DO-220AA (SMP)

MAJOR RATINGS AND CHARACTERISTICS							
$I_{F(AV)}$	1 A						
V_{RRM}	100 V to 1000 V						
I _R	1 μΑ						
V _F	0.95 V						
T _j max.	150 °C						

FEATURES



- Very low profile typical height of 1.0 mm
- · Ideal for automated placement
- · Glass passivated chip junction
- · Low forward voltage drop
- · Low thermal resistance
- Meets MSL level 1, per J-STD-020C, LF max peak of 260 °C
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

General purpose, polarity protection, and railto-rail protection in both consumer and automotive applications.

MECHANICAL DATA

Case: DO-220AA (SMP)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002B and JESD22-B102D

E3 suffix for commercial grade, HE3 suffix for high

reliability grade (AEC Q101 qualified)

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	S1PB	S1PD	S1PG	S1PJ	S1PK	S1PM	UNIT
Device marking code		SB	SD	SG	SJ	SK	SM	
Maximum repetitive peak reverse voltage	V _{RRM}	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	100	200	400	600	800	1000	V
Average forward current	I _{F(AV)} 1.0						Α	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	30					Α	
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150					°C	

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S1PB thru S1PM

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)										
PARAMETER	TEST CONDITIONS		SYMBOL	S1PB	S1PD	S1PG	S1PJ	S1PK	S1PM	UNIT
Maximum instantaneous forward voltage ⁽¹⁾	at $I_F = 1.0 A$, at $I_F = 1.0 A$,	T _j = 25 °C T _j = 125 °C	V _F	1.1 F 0.95					>	
Maximum reverse current (1)	at rated V_R $T_j = 25 ^{\circ}C$ $T_j = 125 ^{\circ}C$		I _R	1.0 1.0 50 100				μΑ		
Typical reverse recovery time	at = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A		t _{rr}	1.8						μs
Typical junction capacitance time	at 4.0 V, 1 MHz		CJ	6.0					pF	

Note:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL S1PB S1PD S1PG S1PJ S1PK S1PM UNIT							UNIT
Typical thermal resistance (1)	$egin{array}{c} R_{ hetaJA} \ R_{ hetaJL} \ R_{ hetaJC} \end{array}$	105 15 20					°C/W	

Note:

(1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 5.0 x 5.0 mm copper pad areas. $R_{\theta JC}$ is measured at the terminal of cathode band. $R_{\theta JC}$ is measured at the top centre of the body

ORDERING INFORMATION (Example)								
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE				
S1PJ-E3/84A	0.024	84A	3000	7" Diameter Plastic Tape & Reel				
S1PJ-E3/85A	0.024	85A	10000	13" Diameter Plastic Tape & Reel				
S1PJHE3/84A (1)	0.024	84A	3000	7" Diameter Plastic Tape & Reel				
S1PJHE3/85A (1)	0.024	85A	10000	13" Diameter Plastic Tape & Reel				

Note:

(1) Automotive grade AEC Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

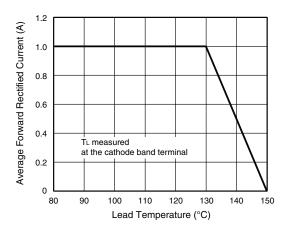


Figure 1. Maximum Forward Current Derating Curve

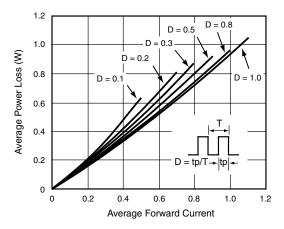


Figure 2. Forward Power Loss Characteristics

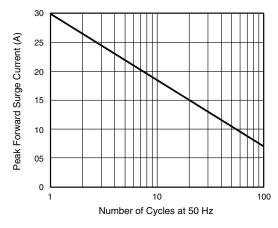


Figure 3. Maximum Non-Repetitive Peak Forward Surge Current

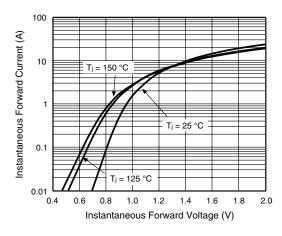


Figure 4. Typical Instantaneous Forward Characteristics

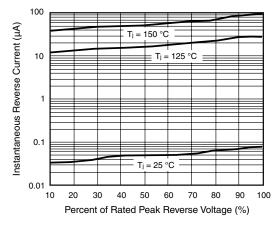


Figure 5. Typical Reverse Leakage Characteristics

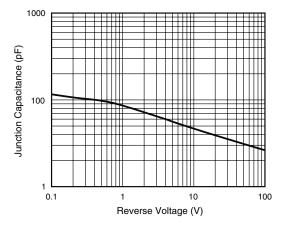


Figure 6. Typical Junction Capacitance

S1PB thru S1PM

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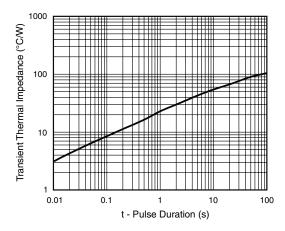
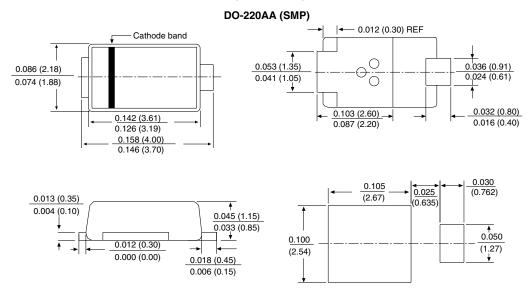


Figure 7. Typical Transient Thermal Impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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